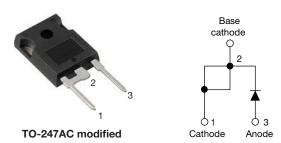


Vishay Semiconductors

High Voltage Input Rectifier Diode, 60 A



PRODUCT SUMMARY					
Package	TO-247AC modified (2 pins)				
I _{F(AV)}	60 A				
V _R	800 V to 1200 V				
V _F at I _F	1.09 V				
I _{FSM}	1000 A				
T _J max.	150 °C				
Diode variation	Single die				

FEATURES

- Very low forward voltage drop
- 150 °C max. operating junction temperature
- · Glass passivated pellet chip junction
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

APPLICATIONS

- Input rectification
- Vishay Semiconductors switches and output rectifiers which are available in identical package outlines

DESCRIPTION

High voltage rectifiers optimized for very low forward voltage drop with moderate leakage.

These devices are intended for use in main rectification (single or three phase bridge).

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS VALUES UNITS					
I _{F(AV)}	Sinusoidal waveform	60	А			
V _{RRM}		800/1200	V			
I _{FSM}		1000	А			
V _F	60 A, T _J = 25 °C	1.09	V			
TJ		-40 to +150	°C			

VOLTAGE RATINGS						
PART NUMBER V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V		V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA			
VS-60EPS08PbF, VS-60EPS08-M3	800	900	1			
VS-60EPS12PbF, VS-60EPS12-M3	1200	1300	1			

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum average forward current	I _{F(AV)}	T_{C} = 118 °C, 180° conduction half sine wave	60			
Maximum peak one cycle		10 ms sine pulse, rated V _{RRM} applied	840	A		
non-repetitive surge current	IFSM	10 ms sine pulse, no voltage reapplied	1000			
Maximum 1 ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	3530	A ² s		
Maximum I ² t for fusing		10 ms sine pulse, no voltage reapplied	4220	A ² S		
Maximum I ² √t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	42 200	A²√s		

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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CON	IDITIONS	VALUES	UNITS		
Maximum forward voltage drop	V	30 A, T _J = 25 °C		1.0	V		
	V _{FM}	60 A, T _J = 25 °C		1.09	V		
Forward slope resistance	rt	T 150 %O		3.96	mΩ		
Threshold voltage	V _{F(TO)}	T _J = 150 °C		0.74	V		
			V - Potod V	0.1	٣٨		
Maximum reverse leakage current	IRM	T _J = 150 °C	$V_R = Rated V_{RRM}$	1.0	mA		

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	PARAMETER		SYMBOL TEST CONDITIONS		UNITS	
Maximum junction and storage temperature range		T _J , T _{Stg}		-40 to +150	°C	
Maximum thermal resistance, unction to case		R _{thJC}	DC operation	0.35		
Maximum thermal resistance, junction to ambient		R _{thJA}		40	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased	0.2		
Approvimate weight				6	g	
Approximate weight				0.21	oz.	
Mounting torque	minimum			6 (5)	kgf ⋅ cm	
Mounting torque	maximum			12 (10)	(lbf ⋅ in)	
Marking davias			Coop atula TO 247AC modified (IEDEC)	60EPS08		
Marking device			Case style TO-247AC modified (JEDEC)		60EPS12	



VS-60EPS..PbF Series, VS-60EPS..-M3 Series

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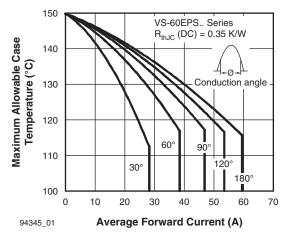


Fig. 1 - Current Rating Characteristics

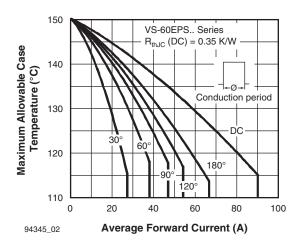


Fig. 2 - Current Rating Characteristics

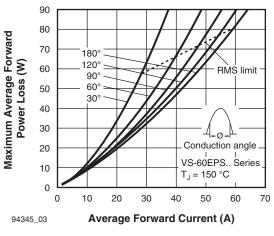


Fig. 3 - Forward Power Loss Characteristics

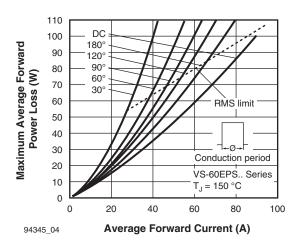


Fig. 4 - Forward Power Loss Characteristics

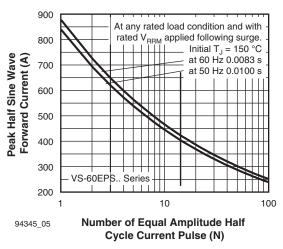


Fig. 5 - Maximum Non-Repetitive Surge Current

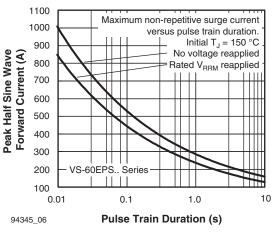


Fig. 6 - Maximum Non-Repetitive Surge Current

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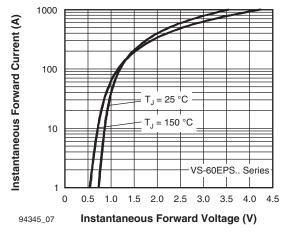


Fig. 7 - Forward Voltage Drop Characteristics

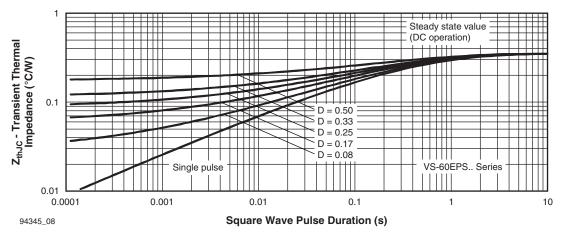
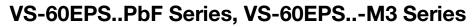


Fig. 8 - Thermal Impedance ZthJC Characteristics



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ORDERING INFORMATION TABLE

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VISHA

Device code	VS-	60	E	Р	S	12	PbF
		2	3	4	5	6	7
	1	· Cur · Circ E = · Pac	rent ratii uit confi single d kage:	niconduc ng (60 = iguratior liode AC moc	60 A) n:	duct	
	5 - 6 -	S =		con: d recove le x 100	-		
	7 -	PbF	= lead	ital digit: (Pb)-free jen-free,	e and R		-

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-60EPS08PbF	25	500	Antistatic plastic tubes				
VS-60EPS08-M3	25	500	Antistatic plastic tubes				
VS-60EPS12PbF	25	500	Antistatic plastic tubes				
VS-60EPS12-M3	25	500	Antistatic plastic tubes				

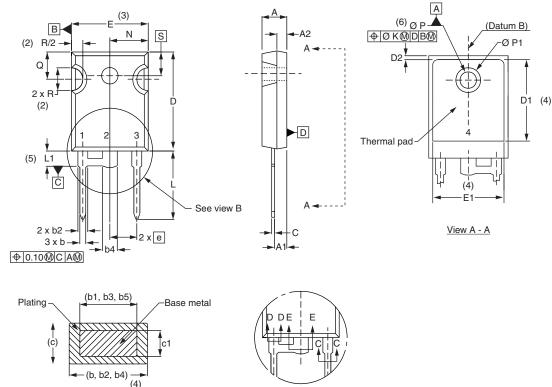
LINKS TO RELATED DOCUMENTS					
Dimensions		www.vishay.com/doc?95541			
Deut mendeiner information	TO-247AC modified PbF	www.vishay.com/doc?95255			
Part marking information	TO-247AC modified -M3	www.vishay.com/doc?95442			
SPICE model		www.vishay.com/doc?95625			





TO-247 - 50 mils L/F modified

DIMENSIONS in millimeters and inches



Section C - C, D - D, E - E



View	В

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.17	1.37	0.046	0.054	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
с	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIN	MILLIMETERS		HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.35	0.020	0.053	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	BSC	
ØК	0.254		0.0)10	
L	14.20	16.10	0.559	0.634	
L1	3.71	4.29	0.146	0.169	
N	7.62	BSC	0.3		
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	7.39	-	0.291	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51	BSC	0.217	BSC	

Notes

- ⁽¹⁾ Dimensioning and tolerance per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- ⁽⁴⁾ Thermal pad contour optional with dimensions D1 and E1
- ⁽⁵⁾ Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension c and Q

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